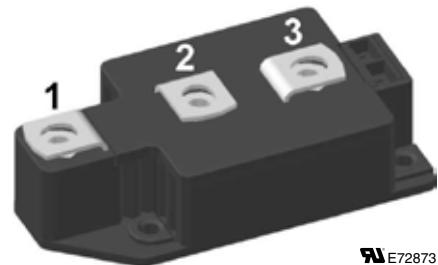
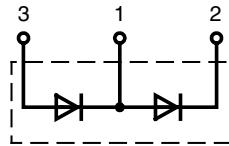


# High Power Diode Modules

**I<sub>FRSM</sub>** = 2x 450 A  
**I<sub>FAVM</sub>** = 2x 290 A  
**V<sub>RRM</sub>** = 1200-1600 V

V <sub>RSM</sub> V	V <sub>RRM</sub> V	Type
1300	1200	MDD 250-12N1
1500	1400	MDD 250-14N1
1700	1600	MDD 250-16N1



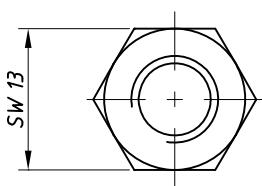
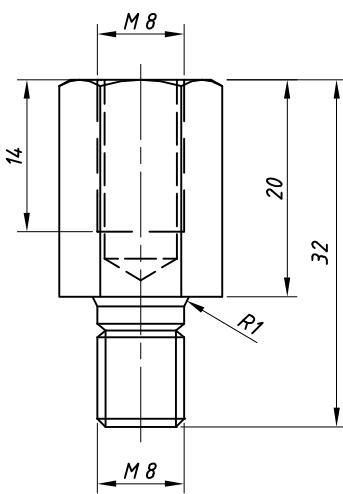
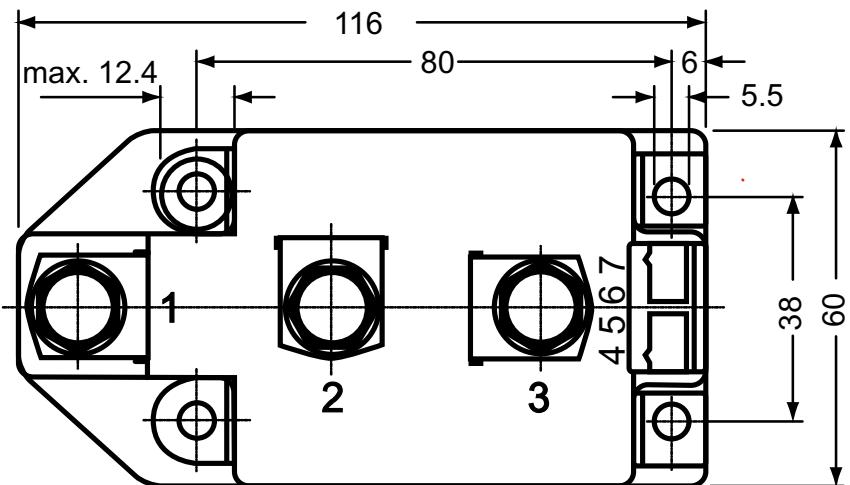
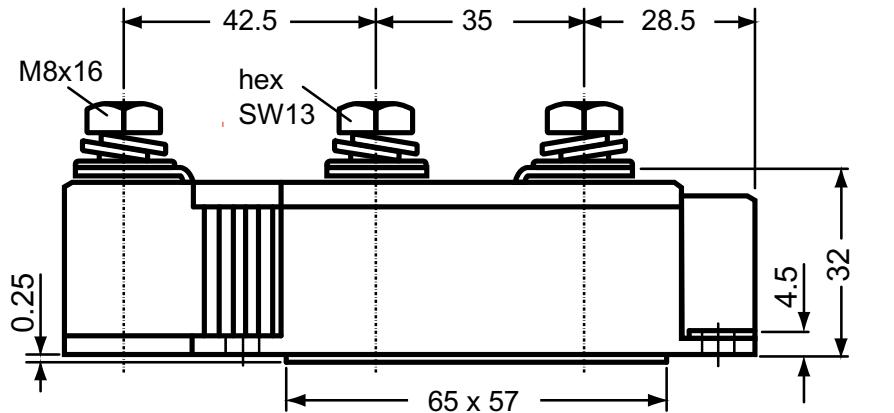
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Symbol	Conditions	Maximum Ratings		
I <sub>FRMS</sub>	T <sub>VJ</sub> = T <sub>VJM</sub>	450	A	
I <sub>FAVM</sub>	T <sub>C</sub> = 100°C; 180° sine	290	A	
I <sub>FSM</sub>	T <sub>VJ</sub> = 45°C; t = 10 ms (50 Hz) V <sub>R</sub> = 0 t = 8.3 ms (60 Hz)	11	kA	
	T <sub>VJ</sub> = T <sub>VJM</sub> ; t = 10 ms (50 Hz) V <sub>R</sub> = 0 t = 8.3 ms (60 Hz)	9	kA	
		11,7	kA	
I <sup>2</sup> t	T <sub>VJ</sub> = 45°C; t = 10 ms (50 Hz) V <sub>R</sub> = 0 t = 8.3 ms (60 Hz)	605	kA <sup>2</sup> s	
	T <sub>VJ</sub> = T <sub>VJM</sub> ; t = 10 ms (50 Hz) V <sub>R</sub> = 0 t = 8.3 ms (60 Hz)	405	kA <sup>2</sup> s	
		560	kA <sup>2</sup> s	
		380	kA <sup>2</sup> s	
T <sub>VJ</sub>		-40...+150	°C	
T <sub>VJM</sub>		150	°C	
T <sub>stg</sub>		-40...+125	°C	
V <sub>ISOL</sub>	50/60 Hz, RMS t = 1 min I <sub>ISOL</sub> ≤ 1 mA t = 1 s	3000	V~	
		3600	V~	
M <sub>d</sub>	Mounting torque (M5) Terminal connection torque (M8)	2.5 - 5	Nm	
		12 - 15	Nm	
Weight	Typical including screws	320	g	

Symbol	Conditions	Characteristics Values		
I <sub>RRM</sub>	V <sub>R</sub> = V <sub>RRM</sub> ; T <sub>VJ</sub> = T <sub>VJM</sub>	40	mA	
V <sub>F</sub>	I <sub>F</sub> = 600 A; T <sub>VJ</sub> = 25°C	1.3	V	
V <sub>TO</sub>	For power-loss calculations only	0.75	V	
r <sub>t</sub>	T <sub>VJ</sub> = T <sub>VJM</sub>	0.75	mΩ	
R <sub>thJC</sub>	per diode; DC current	0.129	K/W	
	per module	0.065	K/W	
R <sub>thJK</sub>	per diode; DC current	0.169	K/W	
	per module	0.0845	K/W	
Q <sub>S</sub>	T <sub>VJ</sub> = 125°C; I <sub>F</sub> = 400 A; -di/dt = 50 A/μs	760	μC	
I <sub>RM</sub>		275	A	
d <sub>s</sub>	Creeping distance on surface	12.7	mm	
d <sub>A</sub>	Creepage distance in air	9.6	mm	
a	Maximum allowable acceleration	50	m/s <sup>2</sup>	

Data according to IEC 60747 and refer to a single diode unless otherwise stated.

Dimensions in mm (1 mm = 0.0394")



Threaded spacer for higher Anode /  
Cathode construction:

Type ZY 250 (material brass)

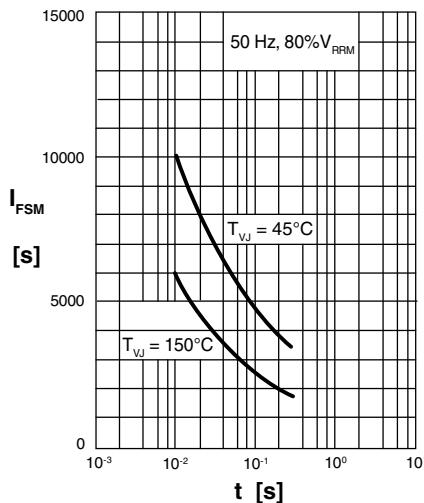


Fig. 1 Surge overload current  
 $I_{FSD}$ : Crest value,  $t$ : duration

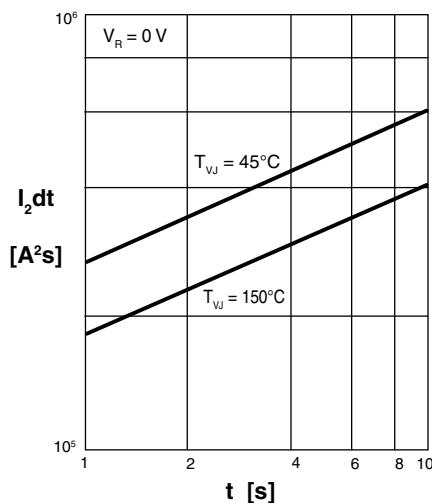


Fig. 2  $I^2 dt$  versus time (1-10 ms)

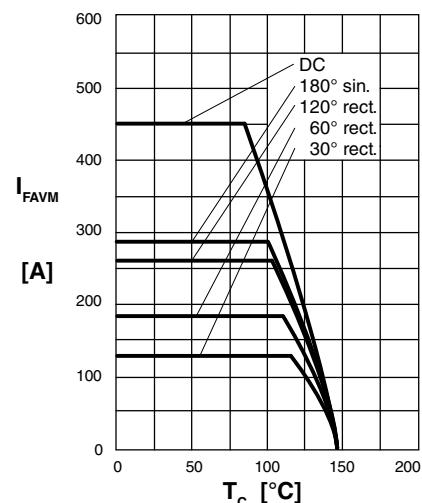


Fig. 2a Maximum forward current  
at case temperature

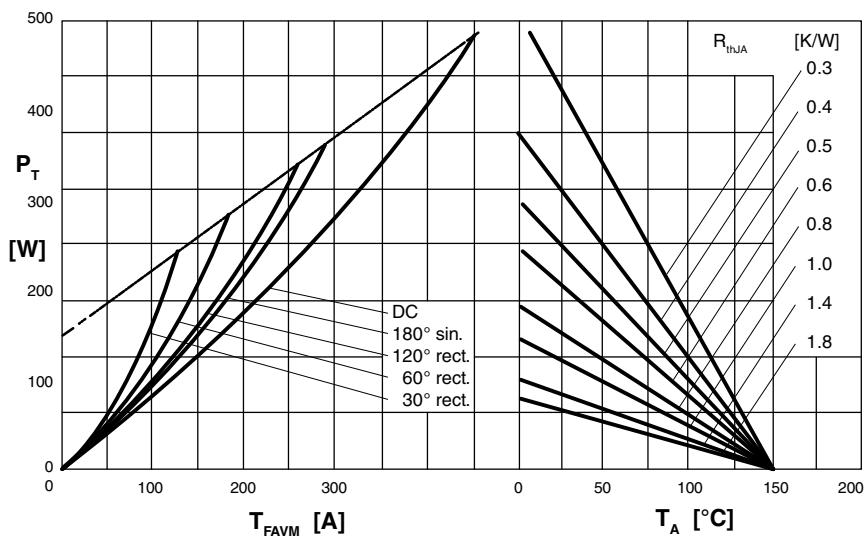
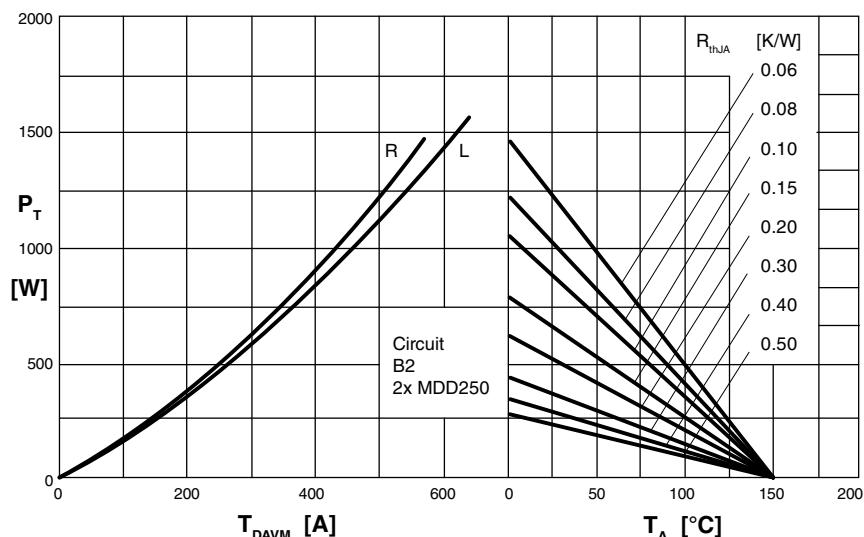


Fig. 3 Power dissipation vs. forward current and ambient temperature (per diode)



R = resistive load  
L = inductive load

Fig. 4 Single phase rectifier bridge: Power dissipation vs. direct output current and ambient

IXYS reserves the right to change limits, test conditions and dimensions.

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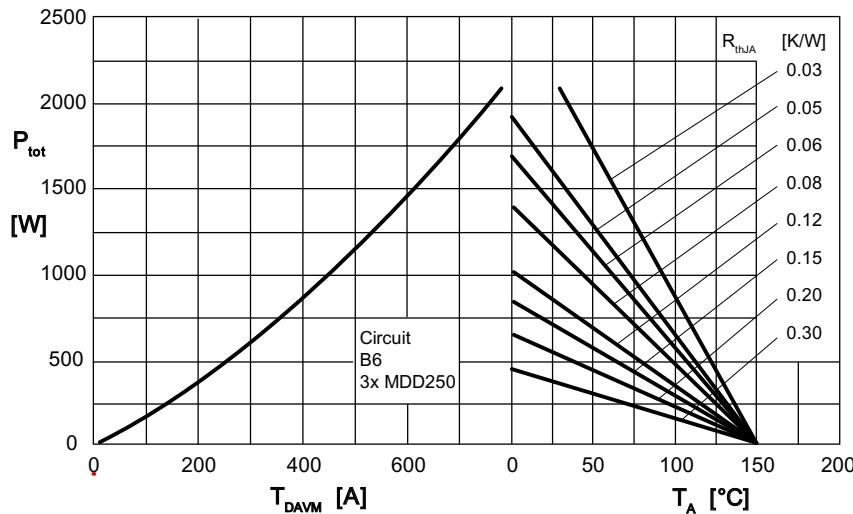


Fig. 5 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

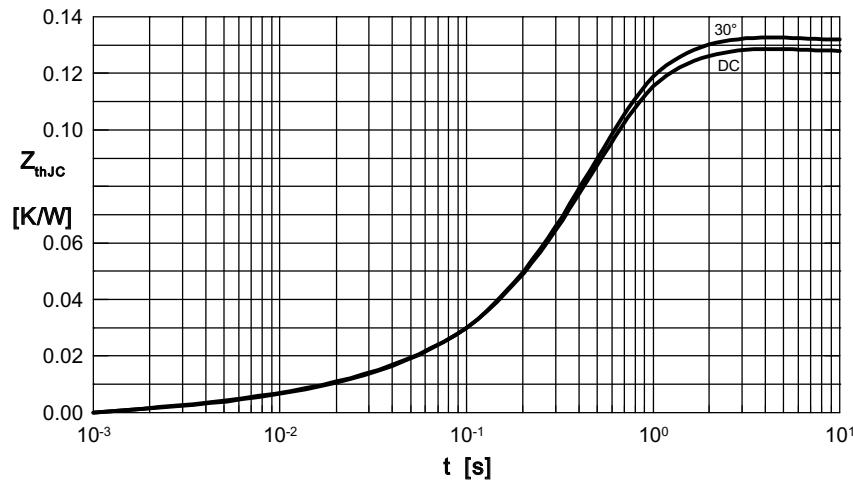


Fig. 7 Transient thermal impedance junction to case (per diode)

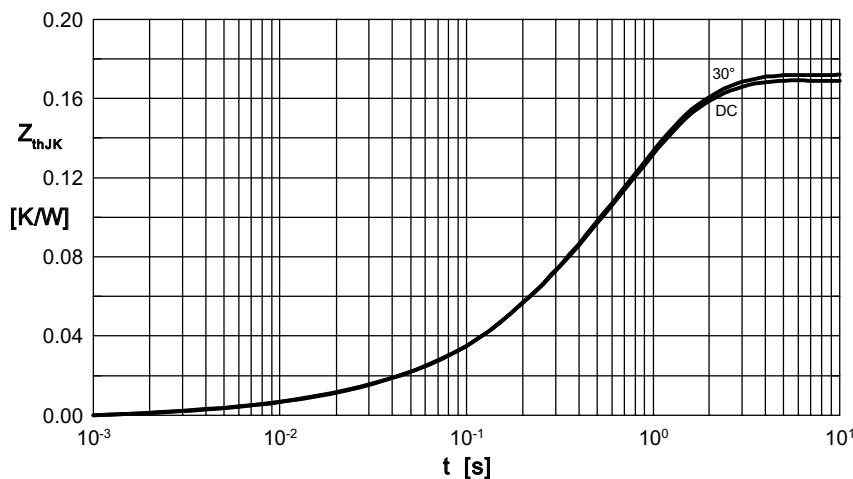


Fig. 8 Transient thermal impedance junction to heatsink (per diode)